

LOW NOISE AMPLIFIER GaAs MMIC

■GENERAL DESCRIPTION

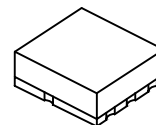
NJG1107HB6 is a Low Noise Amplifier GaAs MMIC designed for GPS. This amplifier provides low noise figure, high gain and high IP3 operated by single low positive power supply.

This amplifier includes internal self-bias circuit and input DC blocking capacitor.

This amplifier can be tuned to wide frequency point (1.5GHz~2.4GHz).

An ultra small and ultra thin package of USB8-B6 is adopted.

■PACKAGE OUTLINE



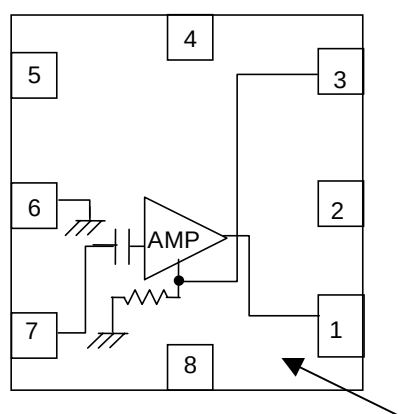
NJG1107HB6

■FEATURES

- | | |
|-----------------------------------|--|
| ●Low voltage operation | +2.7V typ. |
| ●Low current consumption | 2.5mA typ. |
| ●High small signal gain | 17dB typ. @f=1.575GHz |
| ●Low noise figure | 1.1dB typ. @f=1.575GHz |
| ●High Input IP3 | -4.0dBm typ. @f=1.575+1.5751GHz |
| ●Ultra small & ultra thin package | USB8-B6 (Package size: 1.5x1.5x0.55mm) |

■PIN CONFIGURATION

HB6 Type
(Top View)



Pin Connection

1. RF_{OUT}
2. N/C
3. EXTCAP
4. N/C
5. N/C
6. GND
7. RF_{IN}
8. N/C

Orientation Mark

Note: Specifications and description listed in this catalog are subject to change without prior notice.

NJG1107HB6

■ABSOLUTE MAXIMUM RATINGS

($T_a=+25^{\circ}\text{C}$, $Z_s=Z_l=50\text{ohm}$)

PARAMETER	SYMBOL	CONDITIONS	RATINGS	UNIT
Drain Voltage	V_{DD}		6.0	V
Input Power	Pin	$V_{DD}=2.7\text{V}$	+15	dBm
Power Dissipation	P_D	At on PCB board	135	mW
Operating Temp.	T_{opr}		-40~+85	$^{\circ}\text{C}$
Storage Temp.	T_{stg}		-55~+150	$^{\circ}\text{C}$

■ELECTRICAL CHARACTERISTICS

($V_{DD}=2.7\text{V}$, $f=1.575\text{GHz}$, $T_a=+25^{\circ}\text{C}$, $Z_s=Z_l=50\text{ohm}$, TEST CIRCUIT)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Operating Frequency	freq1		1.57	1.575	1.58	GHz
Drain Voltage	V_{DD}		2.5	2.7	5.5	V
Operating Current	I_{DD}	RF OFF	-	2.5	3.2	mA
Small Signal Gain	Gain		15.0	17.0	-	dB
Noise Figure	NF		-	1.1	1.3	dB
Pin at 1dB Gain Compression point	$P_{-1\text{dB}}$		-20.0	-16.0	-	dBm
Input 3rd Order Intercept Point	IIP3	$f=1.575+1.5751\text{GHz}$ $RFin=-35\text{dBm}$	-7.0	-4.0	-	dBm
RF Input Port VSWR	$VSWR_i$		-	1.6	2.0	
RF Output Port VSWR	$VSWR_o$			1.6	2.2	

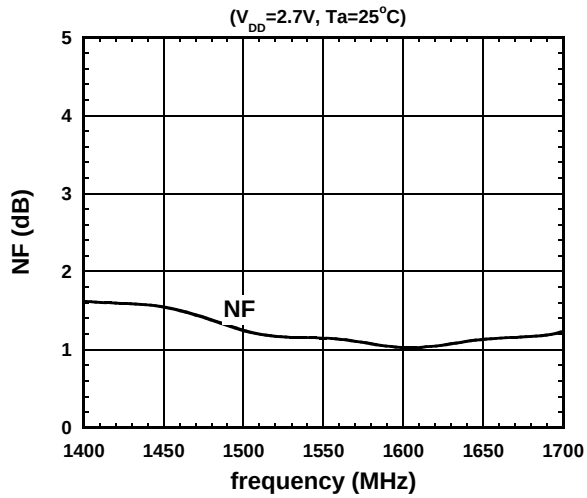
■PIN CONFIGURATION

Pin	Function	Description
1	Rfout	RF output and voltage supply pin. External matching circuits and a bypass capacitor is required. L3 is a RF choke inductor and C1 is a DC blocking capacitor. These elements are used as output matching circuit. C2 is a bypass capacitor.
2,4,5,8	N/C	Neutral terminal. Should be connected to the ground.
3	EXTCAP	An external bypass capacitor is required.
6	GND	Ground pin. To keep good RF grounding performance, please use multiple via holes to connect with ground plane and this pin.
7	Rfin	RF input pin. A DC blocking capacitor is not required. An external matching circuit is required.

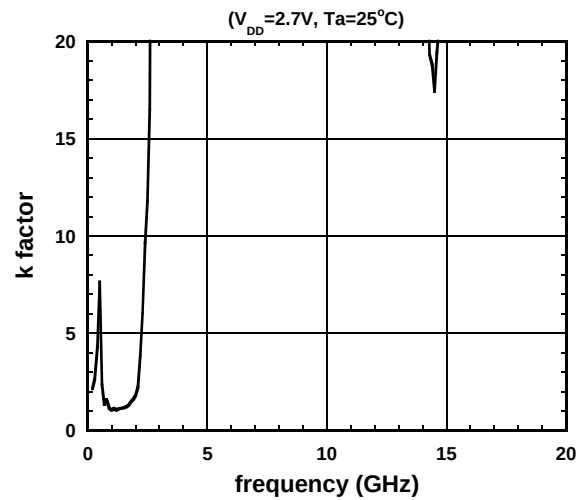
NJG1107HB6

TYPICAL CHARACTERISTICS

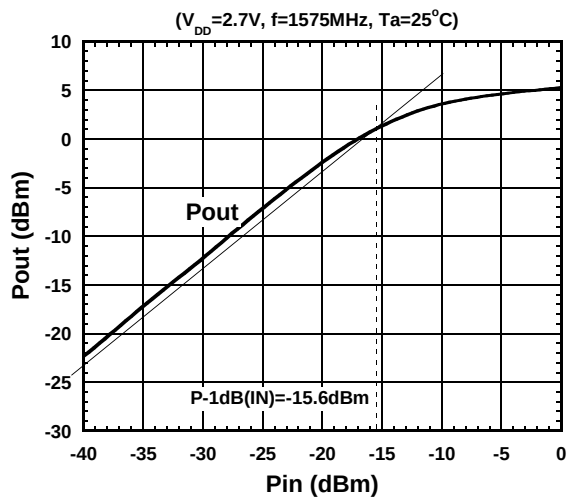
NF vs. frequency



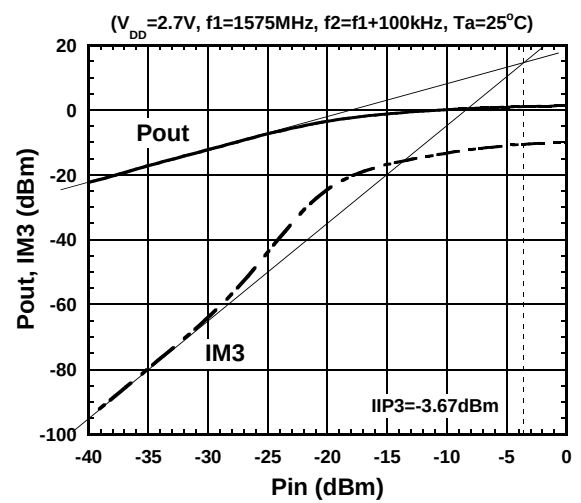
k factor vs. frequency



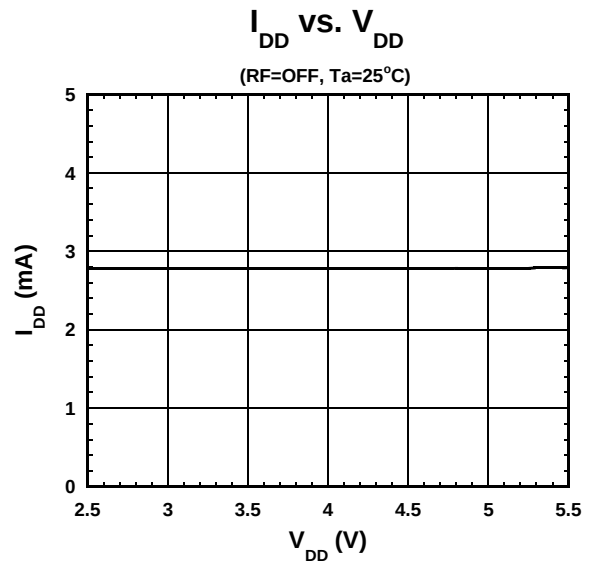
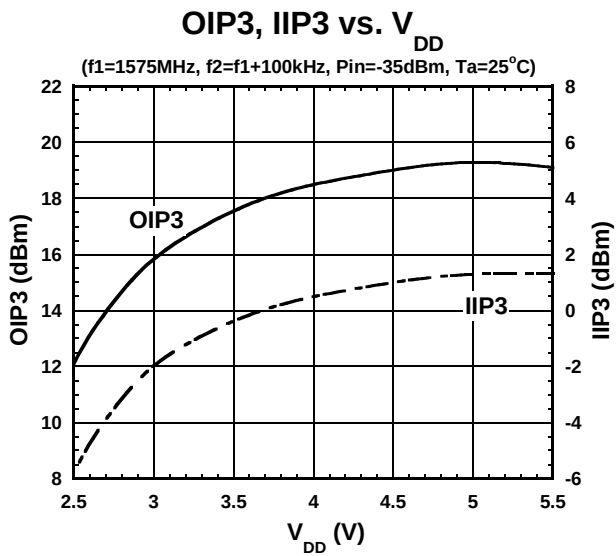
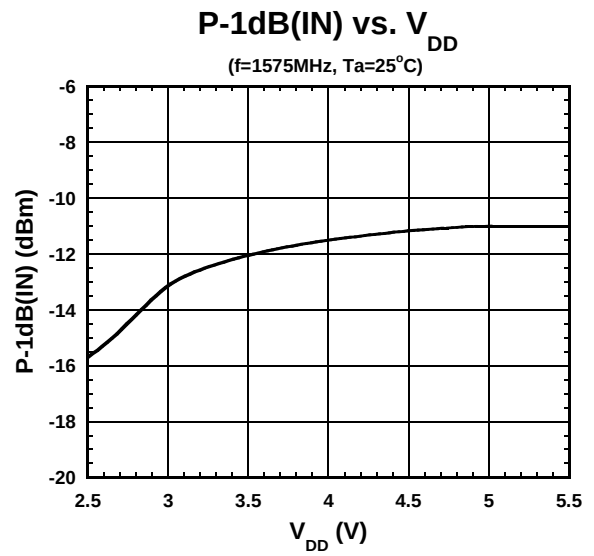
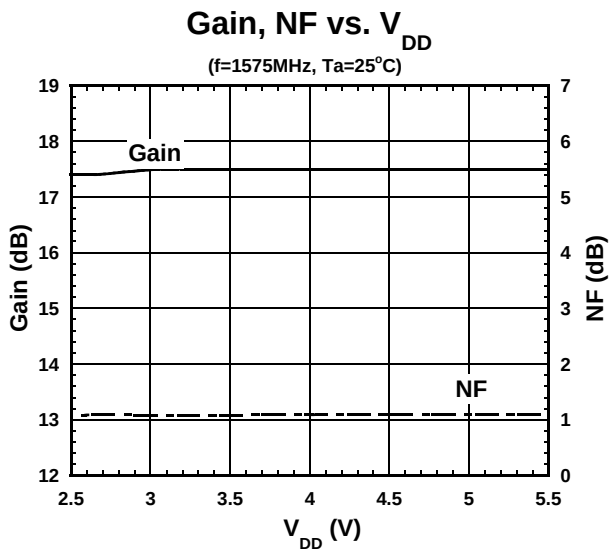
Pout vs. Pin



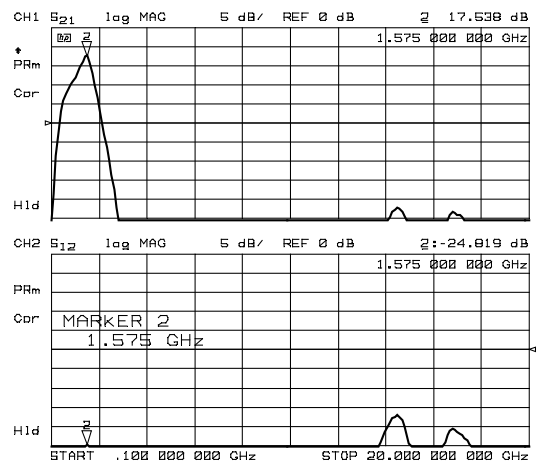
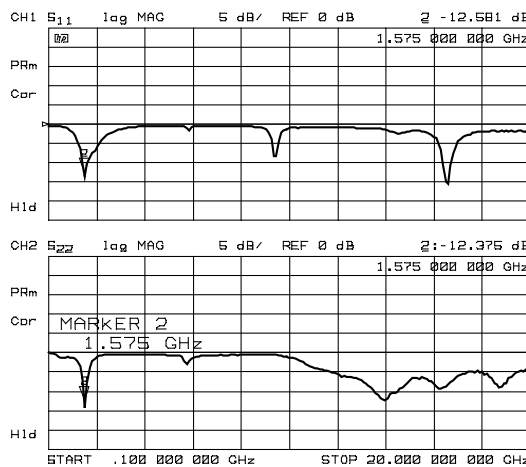
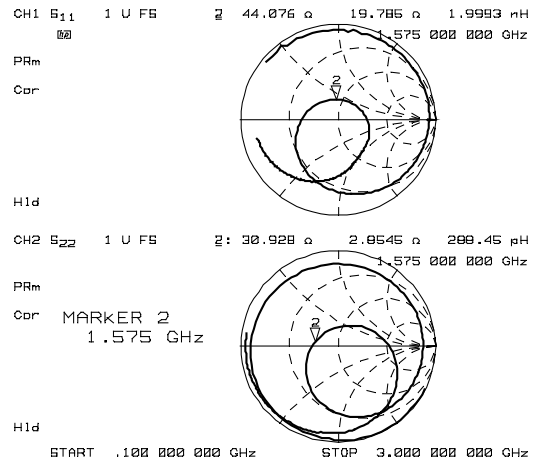
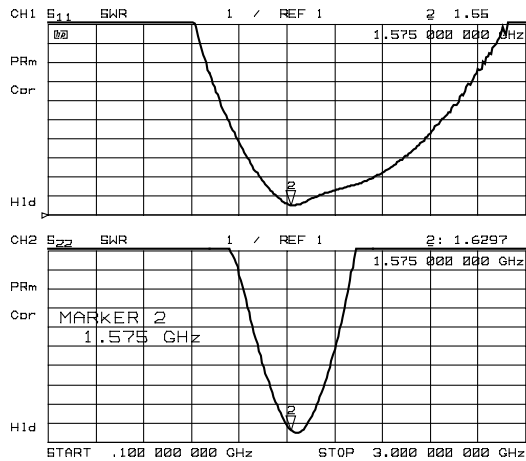
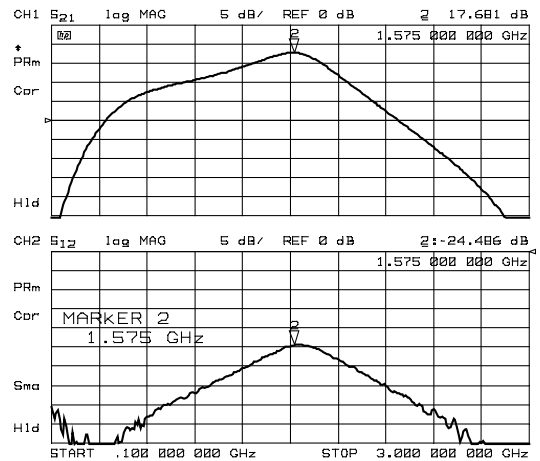
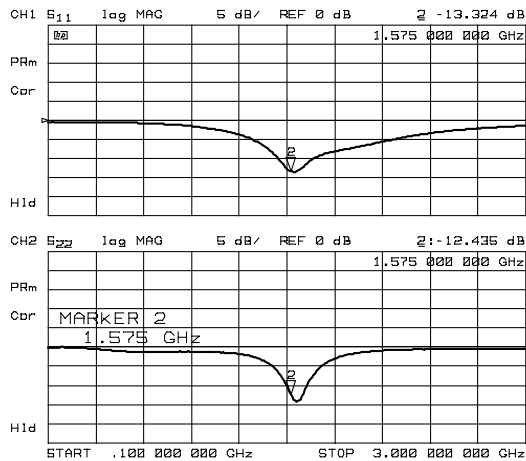
Pout, IM3 vs. Pin



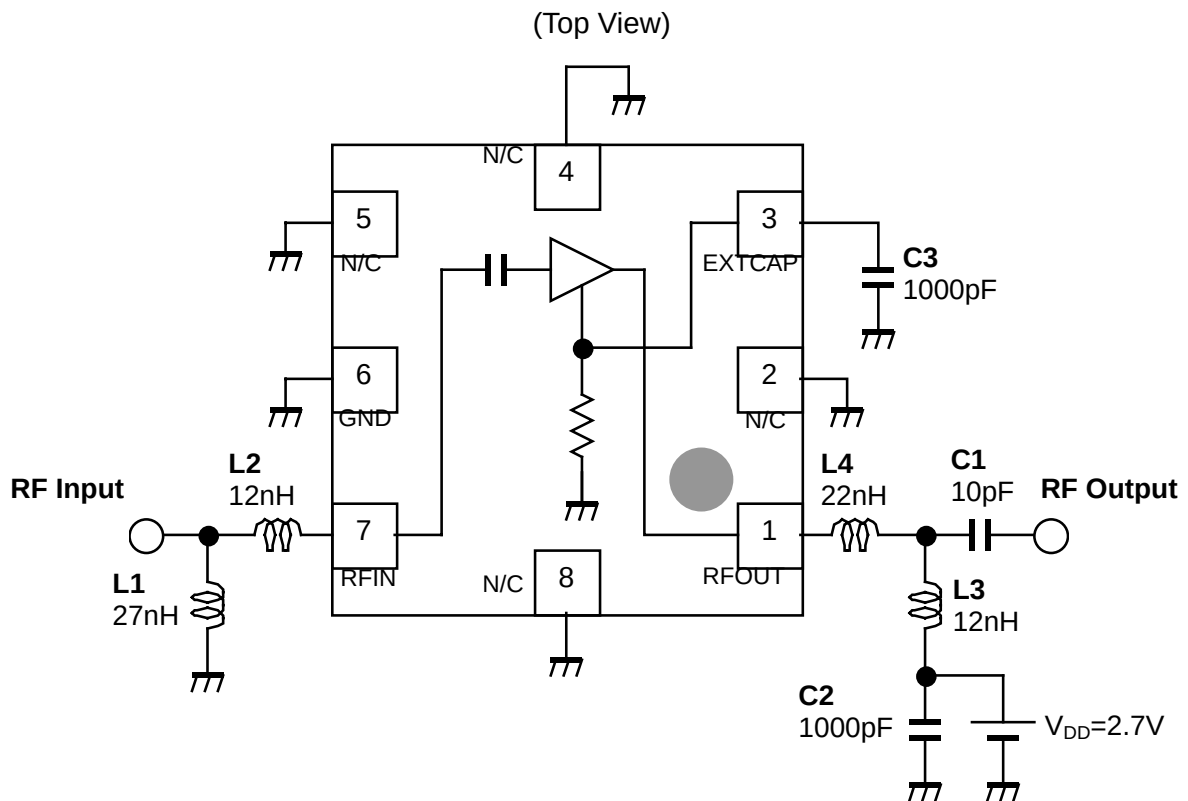
TYPICAL CHARACTERISTICS



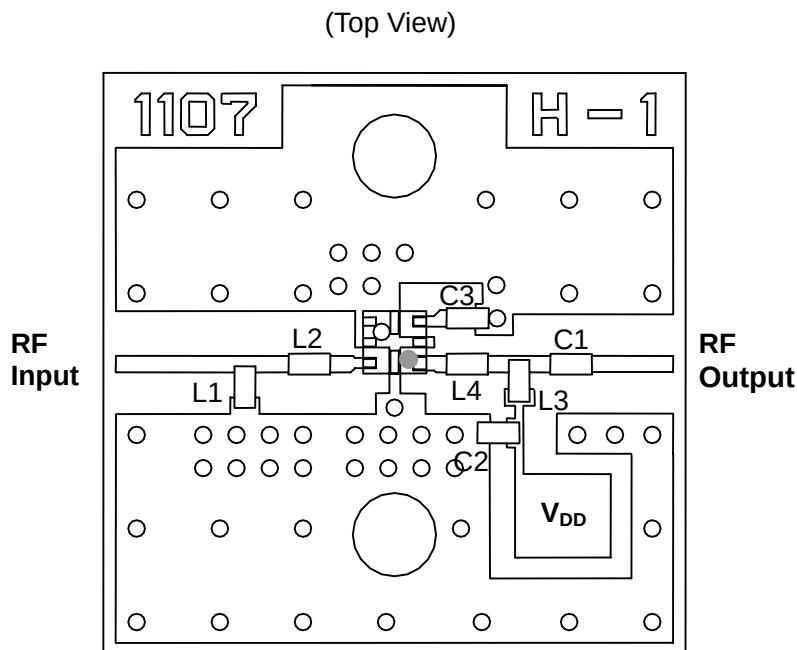
TYPICAL CHARACTERISTICS



TEST CIRCUIT



RECOMMENDED PCB DESIGN

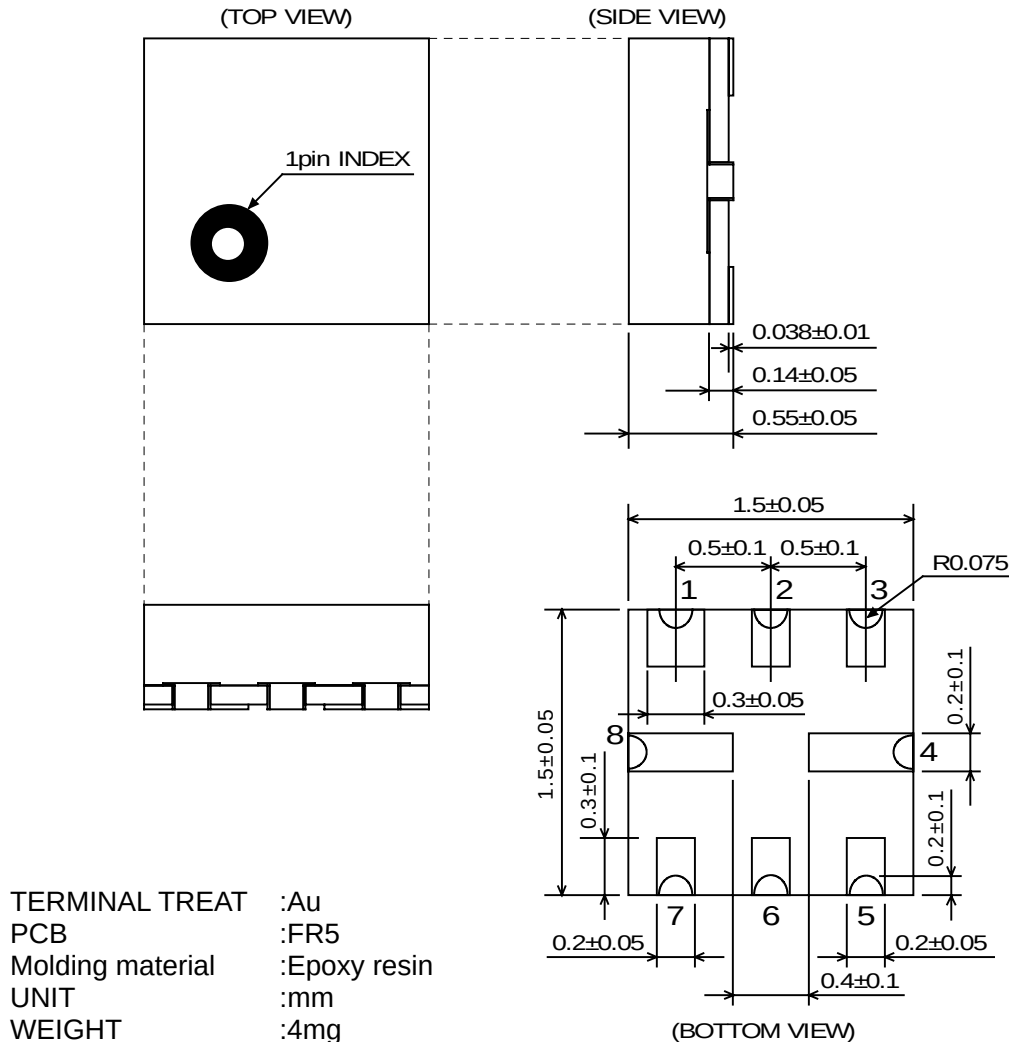


Parts ID	Comment
L1, L3, L4	TDK (MLK1005)
L2	TDK (MLG1005)
C1~C3	MURATA (GRP15)

PCB (FR-4):
 t=0.2mm
 MICROSTRIP LINE WIDTH
 =0.4mm (Z₀=50ohm)
 PCB SIZE=14.0mmX14.0mm

NJG1107HB6

■PACKAGE OUTLINE (USB8-B6)



Cautions on using this product

This product contains Gallium-Arsenide (GaAs) which is a harmful material.

- Do NOT eat or put into mouth.
- Do NOT dispose in fire or break up this product.
- Do NOT chemically make gas or powder with this product.
- To waste this product, please obey the relating law of your country.

[CAUTION]

The specifications on this databook are only given for information, without any guarantee as regards either mistakes or omissions. The application circuits in this databook are described only to show representative usages of the product and not intended for the guarantee or permission of any right including the industrial rights.

This product may be damaged with electric static discharge (ESD) or spike voltage. Please handle with care to avoid these damages.

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

[NJR:](#)

[NJG1107HB6-TE1](#)

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9